91 🖲 📴



4.78 188 -252 3.2±0.1 .126±.004 4.78 .188 .29 .114

mm inch

GU (General Use)-E Type 1-Channel (Form A) 4-pin Type

FEATURES

1. Reinforced insulation 5,000 V type More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

2. Compact 4-pin DIP size The device comes in a compact (W)6.4×(L)4.78×(H)3.2mm (W).252× (L).188×(H).126inch, 4-pin DIP size.

3. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. High sensitivity, low ON resistance Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 25Ω (AQY210EH). Stable operation because there are no metallic contact parts.

PhotoMOS

RELAYS

5. Low-level off state leakage current The SSR has an off state leakage current of several milliamperes, whereas the PhotoMOS relay has only 100 pA even with the rated load voltage of 350 V (AQY210EH).

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Security equipment
- Sensors

TYPES

Туре	I/O isolation voltage	Output rating*			Pa					
				Through hole terminal	Surface-mount terminal			Packing quantity		
		Lood	Lood			Tape and reel packing style			Topo and	
		Load voltage	Load current	Tube pac	king style	Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	Tape and reel	
AC/DC	Reinforced	350 V	130 mA	AQY210EH	AQY210EHA	AQY210EHAX	AQY210EHAZ	1 tube contains 100 pcs.	1 000 peo	
type	5,000 V	400 V	120 mA	AQY214EH	AQY214EHA	AQY214EHAX	AQY214EHAZ	1 batch contains 1,000 pcs.	1,000 pcs.	

*Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the product number "AQY", the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Sym- bol	AQY210EH (A)	AQY214EH (A)	Remarks
	LED forward current	lF	50r		
Input	LED reverse voltage	VR	3'		
	Peak forward current	IFP	1A		f =100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75n		
Output	Load voltage (peak AC)	VL	350 V	400 V	
	Continuous load current	١L	0.13 A	0.12 A	
	Peak load current	Ipeak	0.4 A	0.3 A	100 ms (1 shot), V∟= DC
	Power dissipation	Pout	500mW		
Total power dissipation		Рт	550		
I/O isolation voltage		Viso	5,000		
Temperature Operating		Topr	-40°C to +85°C	Non-condensing at low temperatures	
limits	Storage	Tstg	-40°C to +100°C		

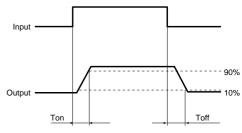
AQY21OEH

For type of connection

	Item		Symbol	AQY210EH (A)	AQY214EH (A)	Condition
	LED operate	Typical		1.2n	I∟=Max.	
	current	Maximum	Fon	3.0n		
lagut	LED turn off current	Minimum	1	0.4n	I∟=Max.	
Input		Typical	Foff	1.1n		
	LED dropout voltage	Typical	VF	1.14 (1.25 V at I⊧=50mA)		l⊧=5mA
		Maximum	VF	1.5V		
	On resistance	Typical	Ron	18Ω	26Ω	I⊧=5mA I∟=Max. Within 1 s on time
Output		Maximum		25Ω	35Ω	
·	Off state leak- age current	Maximum	Leak	1μΑ		l⊧=0 V∟=Max.
	Turn on time*	Typical	Ton -	0.5ms		l⊧=5mA I∟=Max.
		Maximum	Ion	2.0ms		
	Turn off time*	Typical	Toff	0.08ms		l⊧=5mA I∟=Max.
ansfer char-		Maximum	IOT	1.0ms		
acteristics	I/O capacitance	Typical	Ciso	0.8pF		f =1MHz Vв =0
		Maximum	CISO	1.5pF		
	Initial I/O isola- tion resistance	Minimum	Riso	1,000ΜΩ		500V DC

Note: Recommendable LED forward current IF=5mA.

*Turn on/Turn off time



■ For Dimensions, see Page 440.

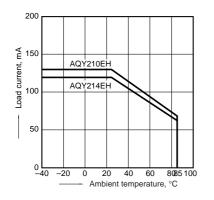
■ For Schematic and Wiring Diagrams, see Page 444.

■ For Cautions for Use, see Page 449.

REFERENCE DATA

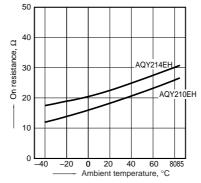
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C –40°F to +185°F



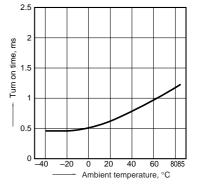
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

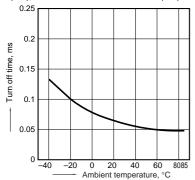
Sample: All types LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



AQY21OEH

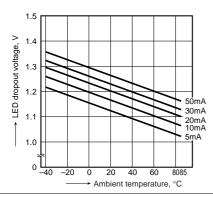
4. Turn off time vs. ambient temperature characteristics

Sample: All types; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



7. LED dropout voltage vs. ambient temperature characteristics

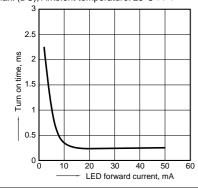
Sample: All types; LED current: 5 to 50 mA



10. LED forward current vs. turn on time characteristics

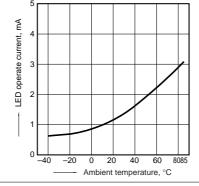
Sample: All types

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



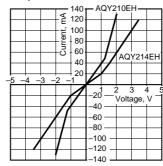
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



8. Voltage vs. current characteristics of output at MOS portion

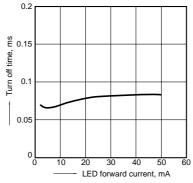
Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



11. LED forward current vs. turn off time characteristics

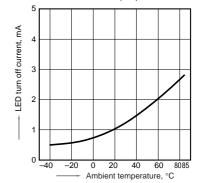
Sample: All types Measured portion: between terminals 3 and 4;

Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



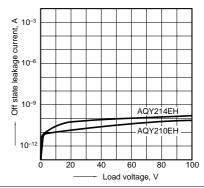
6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



9. Off state leakage current Measured portion: between terminals 3 and 4;

Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance

characteristics

Sample: All types

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

